

LBSS4240LT1G S-LBSS4240LT1G

General Purpose Transistors NPN Silicon

1. FEATURES

- Low collector-emitter saturation voltage
- High current capability
- Improved device reliability due to reduced heat generation
- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.

2. APPLICATIONS

- Supply line switching circuits
- Battery management applications
- DC/DC converter applications
- Strobe flash units
- Heavy duty battery powered equipment (motor and lamp drivers).

3. DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping		
LBSS4240LT1G	ZE	3000/Tape&Reel		
LBSS4240LT3G	ZE	10000/Tape&Reel		

4. MAXIMUM RATINGS(Ta = 25°C)

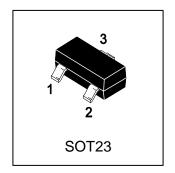
	/		
Parameter	Symbol	Limits	Unit
Collector-Emitter Voltage	VCEO	40	V
Collector-Base voltage	VCBO	40	V
Emitter-Base Voltage	VEBO	5	V
Collector current-continuoun	IC	2	Α
Peak collector current(tp < 1 ms)	ICM	6	Α
Total power dissipation	PD	0.3	W
Junction temperature	TJ	-55~+150	$^{\circ}$
Storage temperature	TSTG	-55~+150	$^{\circ}$

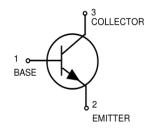
5. THERMAL CHARACTERISTICS

Parameter		Symbol	Value	Unit
Thermal resistance from junction to ambient	(Note 1)	RθJA	417	°C/W
in free air	(Note 2)	INUUA	260	°C/W
Thermal resistance from junction to case(Note 1)		RθJC	150	°C/W

^{1.30.0}mm×25.0mm×1.6mm(FR4),Thickness of copper film:35um

2.Device mounted on a printed-circuit board, single sided copper, tinplated and mounted pad for collector 1 cm².





1/5

LBSS4240LT1G,S-LBSS4240LT1G General Purpose Transistors NPN Silicon

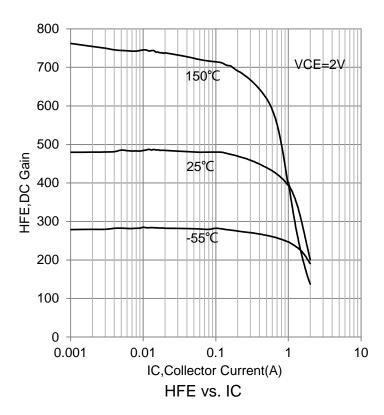
6. ELECTRICAL CHARACTERISTICS (Ta= 25°C)

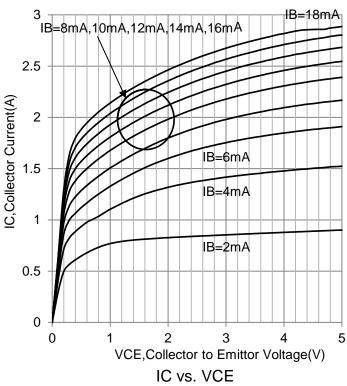
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Collector–Emitter Breakdown Voltage	VBR(CEO)	40	-	-	V
(IC= 10mA,IB= 0A)					
Collector–Base Breakdown Voltage	VDD/CDO)	40	-	-	V
(IC= 100μA,IE= 0A)	VBR(CBO)				
Emitter–Base Breakdown Voltage	VBR(EBO)	5	-	-	V
(IE= 100μA,IC= 0A)	VBK(EBO)				
Collector-Emitter cutoff Current	ICEO			1	μΑ
(IB=0, VCE = 40V)	ICEO	-	-		
Collector-Base cut-off current	ICBO			100	nA
(IE = 0, VCB = 30 V)	ЮВО		-		
Emitter-Base cut-off current	IEBO		_	100	nA
(IC = 0, VEB = 4 V)	ILBO	-	-	100	
DC current gain					
(IC = 100 mA, VCE = 2 V)		350	-	-	
(IC = 500 mA, VCE = 2 V)	hFE	300	-	-	
(IC = 1 A, VCE = 2 V)		300	-	-	
(IC = 2 A, VCE = 2 V)		150	-	-	
Collector-Emitter saturation voltage					
(IC = 100 mA, IB = 1 mA)		-	-	70	
(IC = 500 mA, IB = 50 mA)	VCE(sat)	-	-	100	mV
(IC = 750 mA, IB = 15 mA)	VCL(Sat)	-	-	180	
(IC = 1 A, IB = 50 mA)(Note 3)		-	-	180	
(IC = 2 A, IB = 200 mA)(Note 3)		1	-	320	
Base-Emitter saturation voltage					
(IC = 2 A,IB = 200 mA)(Note 3)	VBE(sat)	-	-	1.1	V
(IC = 2 A,IB = 50 mA)(Note 3)		-	-	1.1	
Base-Emitter turn on voltage	\/BE(on\	-	_	0.75	V
(IC = 100 mA, VCE = 2 V)	VBE(on)	-	-	0.75	V
Collector capacitance	Сс			20	pF
(IE = Ie = 0,VCB = 10 V,f = 1 MHz)	CC	1	-	20	PΓ
Transition frequency	fT	100	-	-	MHz
(IC = 100 mA, VCE = 10 V, f = 100 MHz)		100			

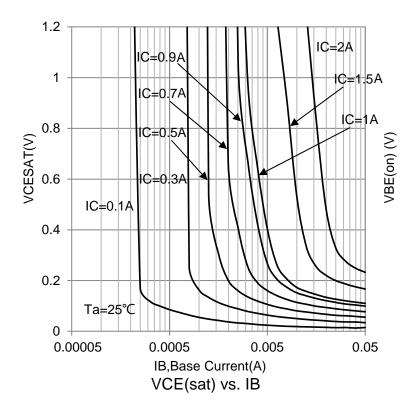
^{3.} Pulse test: t p \leq 300 μ s, $\delta \leq$ 0.02.

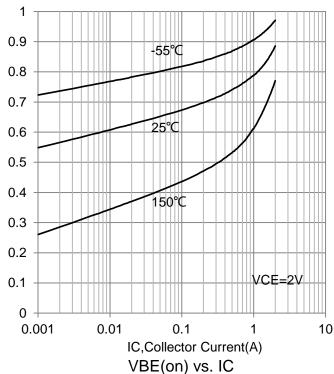


7. ELECTRICAL CHARACTERISTICS CURVES (Ta= 25°C)



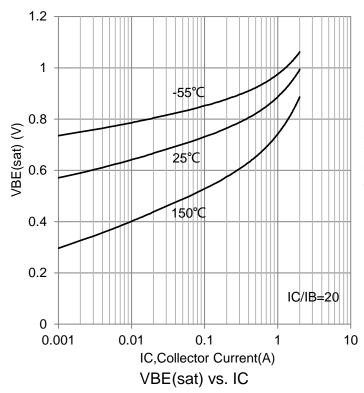


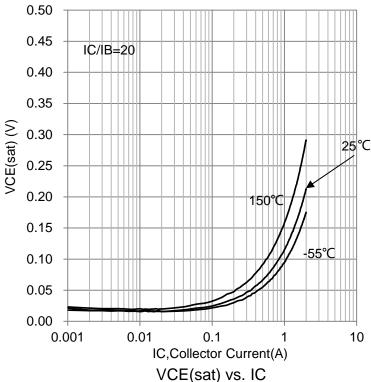






7. ELECTRICAL CHARACTERISTICS CURVES (Ta= 25°C)(Con.)



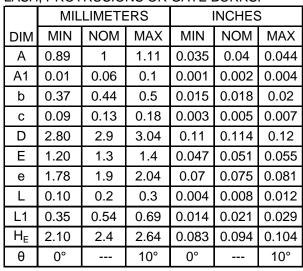


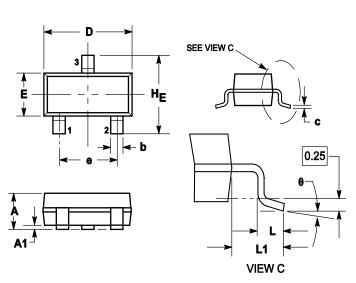
LBSS4240LT1G,S-LBSS4240LT1G General Purpose Transistors NPN Silicon

8.OUTLINE AND DIMENSIONS

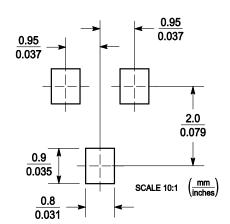
Notes:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.





9.SOLDERING FOOTPRINT





DISCLAIMER

- Curve guarantee in the specification. The curve of test items with electric parameter is used as quality guarantee. The curve of test items without electric parameter is used as reference only.
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